ON Semiconductor

Is Now

Onsemí

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Dual SPST Analog Switch, Low Voltage, Single Supply

The NLAS325 is a dual SPST (Single Pole, Single Throw) switch, similar to 1/2 a standard 4066. The device permits the independent selection of 2 analog/digital signals. Available in the Ultra–Small 8 package.

The use of advanced 0.6 μ CMOS process, improves the R_{ON} resistance considerably compared to older higher voltage technologies.

Features

- On Resistance is 20 Ω Typical at 5.0 V
- Matching is < 1.0 Ω Between Sections
- 2.0–6.0 V Operating Range
- Ultra Low < 5.0 pC Charge Injection
- Ultra Low Leakage < 1.0 nA at 5.0 V, 25°C
- Wide Bandwidth > 200 MHz, -3.0 dB
- 2000 V ESD (HBM)
- R_{ON} Flatness $\pm 6.0 \Omega$ at 5.0 V
- Independent Enables; One Positive, One Negative
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

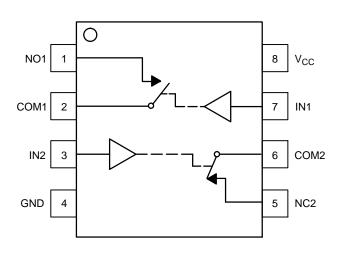
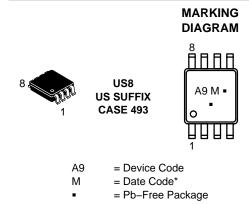


Figure 1. Pinout



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(Note: Microdot may be in either location)

PIN ASSIGNMENT

1	NO1
2	COM1
3	IN2
4	GND
5	NC2
6	COM2
7	IN1
8	V _{CC}

FUNCTION TABLE

On/Off Enable Input				
L	Off	On		
н	On	Off		

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		-0.5 to +7.0	V
V _O	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND	-50	mA
lo	DC Output Sink Current		± 50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1.0 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature under Bias		+ 150	°C
θ_{JA}	Thermal Resistance (Note 1)		250	°C/W
PD	Power Dissipation in Still Air at 85°C		250	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating Oxyge	n Index: 28 to 34	UL 94 V–0 @ 0.125 in	
V _{ESD}	Machin	y Model (Note 2) e Model (Note 3) e Model (Note 4)	> 2000 > 200 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

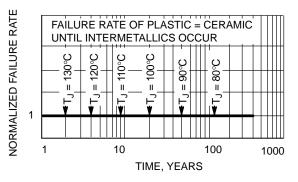
RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	DC Supply Voltage	2.0	5.5	V	
V _{IN}	Digital Select Input Voltage	GND	5.5	V	
V _{IS}	Analog Input Voltage (NC, NO, COM)		GND	V _{CC}	V
T _A	Operating Temperature Range		- 55	+ 125	°C
t _r , t _f	Input Rise or Fall Time, SELECT V	$C_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $C_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0





	1			Guaranteed Limit			
Symbol	Parameter	Condition	V _{CC}	-55°C to 25°C	<85°C	<125°C	Unit
VIH	Minimum High–Level Input		2.0	1.5	1.5	1.5	V
	Voltage, Select Inputs		2.5	1.9	1.9	1.9	
			3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V _{IL}	Maximum Low-Level Input		2.0	0.5	0.5	0.5	V
	Voltage, Select Inputs		2.5	0.6	0.6	0.6	
			3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I _{IN}	Maximum Input Leakage Current, Select Inputs	V _{IN} = 5.5 V or GND	0 V to 5.5 V	±0.2	±2.0	±2.0	μΑ
I _{CC}	Maximum Quiescent Supply Current	Select and $V_{IS} = V_{CC}$ or GND	5.5	4.0	4.0	8.0	μΑ

DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

DC ELECTRICAL CHARACTERISTICS – Analog Section

				Guaranteed Limit		t	
Symbol	Parameter	Condition	v_{cc}	-55°C to 25°C	<85°C	<125°C	Unit
R _{ON}	Maximum "ON" Resistance (Figures 16 – 22)		2.5 3.0 4.5 5.5	85 45 30 25	95 50 35 30	105 55 40 35	Ω
R _{FLAT(ON)}	ON Resistance Flatness (Figures 16 – 22)	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{IN}I \le 10 \text{ mA}$ $V_{IS} = 1.0 \text{ V}, 2.0 \text{ V}, 3.5 \text{ V}$	4.5	4.0	4.0	5.0	Ω
I _{NC(OFF)} I _{NO(OFF)}	NO or NC Off Leakage Current (Figure 8)	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $V_{NO} \text{ or } V_{NC} = 1.0 V_{COM} 4.5 V$	5.5	1.0	10	100	nA
I _{COM} (ON)	COM ON Leakage Current (Figure 8)	$\begin{split} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NC} \text{ floating or } \\ V_{NO} \ 1.0 \ V \text{ or } 4.5 \ V \text{ with } V_{NO} \text{ floating } \\ V_{COM} &= 1.0 \ V \text{ or } 4.5 \ V \end{split}$	5.5	1.0	10	100	nA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

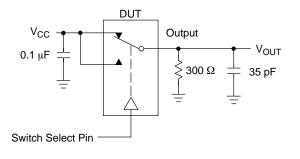
						Guaranteed Maximum Limit						
			V _{CC}	VIS	- 55	5°C to 2	25°C	<8	5°C	<12	25°C	
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Мах	Min	Max	Unit
t _{ON}	Turn–On Time	R_L = 300 Ω, C_L = 35 pF	2.5	2.0	5.0	23	35	5.0	38	5.0	41	ns
	(Figures 11 and 12)	(Figures 4 and 5)	3.0	2.0	5.0	16	24	5.0	27	5.0	30	
			4.5	3.0	2.0	11	16	2.0	19	2.0	22	
			5.5	3.0	2.0	9.0	14	2.0	17	2.0	20	
t _{OFF}	Turn–Off Time	$R_L = 300 \Omega, C_L = 35 pF$	2.5	2.0	1.0	7.0	12	1.0	15	1.0	18	ns
	(Figures 11 and 12)	(Figures 4 and 5)	3.0	2.0	1.0	5.0	10	1.0	13	1.0	16	
			4.5	3.0	1.0	4.0	6.0	1.0	9.0	1.0	12	
			5.5	3.0	1.0	3.0	5.0	1.0	8.0	1.0	11	
t _{BBM}	Minimum Break-Before-Make	V _{IS} = 3.0 V (Figure 3)	2.5	2.0	1.0	12		1.0		1.0		ns
	Time	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	3.0	2.0	1.0	11		1.0		1.0		
			4.5	3.0	1.0	6.0		1.0		1.0		
			5.5	3.0	1.0	5.0		1.0		1.0		

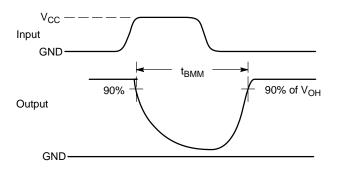
*Typical Characteristics are at 25°C.

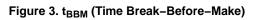
		Typical @ 25, V _{CC} = 5.0 V	
C _{IN}	Maximum Input Capacitance, Select Input	8.0	рF
C _{NO} or C _{NC}	Analog I/O (switch off)	10	
C _{COM}	Common I/O (switch off)	10	
	Feedthrough (switch on)	20	

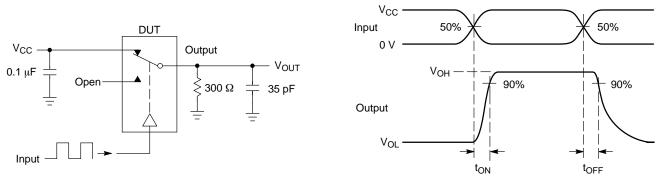
ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

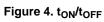
			V _{CC}	Typical	
Symbol	Parameter	Condition	(V)	25°C	Unit
BW	Maximum On–Channel –3.0 dB Bandwidth or Minimum Frequency Response (Figure 10)	$V_{IN} = 0 \text{ dBm}$ V_{IN} centered between V_{CC} and GND (Figure 6)	3.0 4.5 5.5	145 170 175	MHz
V _{ONL}	Maximum Feedthrough On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 6)	3.0 4.5 5.5	-2.0 -2.0 -2.0	dB
V _{ISO}	Off–Channel Isolation (Figure 9)	f = 100 kHz; V_{IS} = 1.0 V RMS V _{IN} centered between V _{CC} and GND (Figure 6)	3.0 4.5 5.5	-93 -93 -93	dB
Q	Charge Injection Select Input to Common I/O (Figure 14)		3.0 5.5	1.5 3.0	pC
THD	Total Harmonic Distortion THD + Noise (Figure 13)	F_{IS} = 20 Hz to 100 kHz, R_L = Rgen = 600 $\Omega,$ C_L = 50 pF V_{IS} = 5.0 V_{PP} sine wave	5.5	0.1	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; V_{IS} = 1.0 V RMS V_{IN} centered between V_{CC} and GND (Figure 6)	5.5 3.0	- 90 - 90	dB

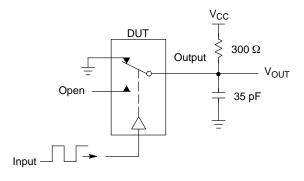


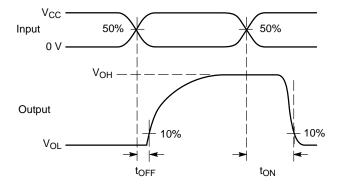


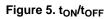


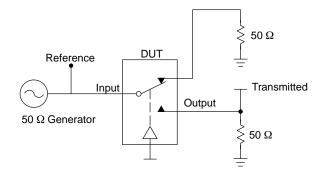








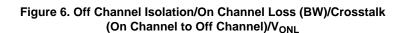


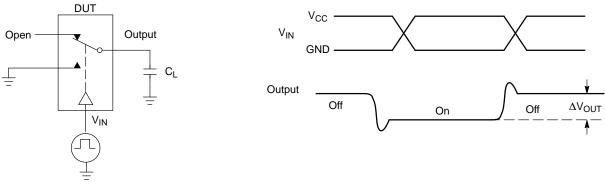


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO} , Bandwidth and V_{ONL} are independent of the input signal direction.

$$\begin{split} & \mathsf{V}_{\mathsf{ISO}} = \mathsf{Off \ Channel \ Isolation} = 20 \ \mathsf{Log} \left(\frac{\mathsf{V}_\mathsf{OUT}}{\mathsf{VIN}} \right) & \mathsf{or} \ \mathsf{V}_\mathsf{IN} \ at \ 100 \ \mathsf{kHz} \\ & \mathsf{V}_\mathsf{ONL} = \mathsf{On \ Channel \ Loss} = 20 \ \mathsf{Log} \left(\frac{\mathsf{V}_\mathsf{OUT}}{\mathsf{VIN}} \right) & \mathsf{for} \ \mathsf{V}_\mathsf{IN} \ at \ 100 \ \mathsf{kHz} \ to \ 50 \ \mathsf{MHz} \end{split}$$

Bandwidth (BW) = the frequency 3.0 dB below V_{ONL} V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω







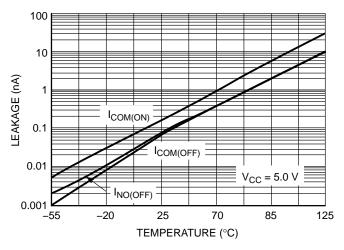


Figure 8. Switch Leakage vs. Temperature

0

1.0

2.0

3.0

4.0

6.0

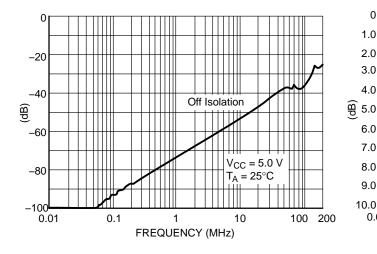
7.0

8.0

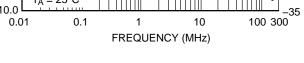
9.0

V_{CC} = 5.0 V

 $T_A = 25^{\circ}C$







Bandwidth (ON–RESPONSE)

PHASE SHIFT

+15

+10

+5

0

_5 (₀) _10 PHASE _15

-20

-25

-30



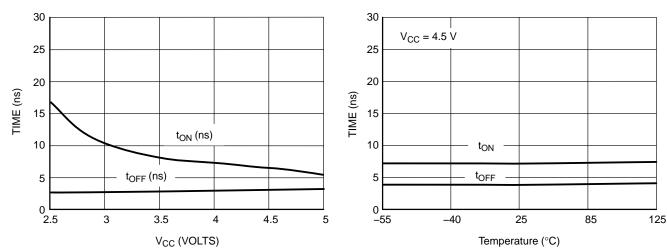
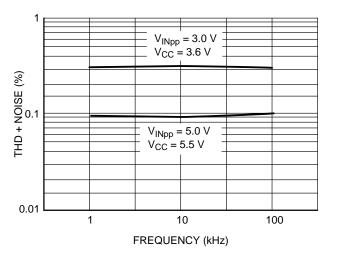


Figure 11. t_{ON} and t_{OFF} vs. V_{CC} at 25°C



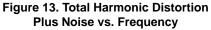
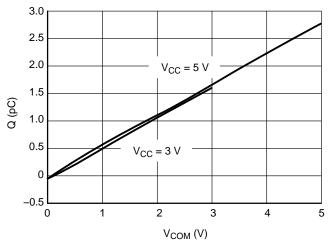
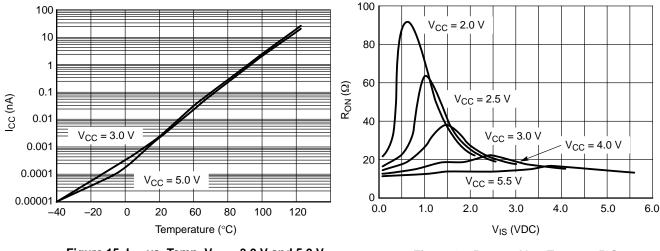


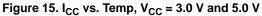
Figure 12. $t_{\mbox{ON}}$ and $t_{\mbox{OFF}}$ vs. Temp

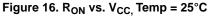


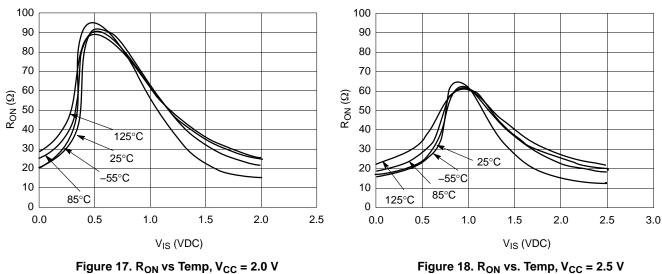












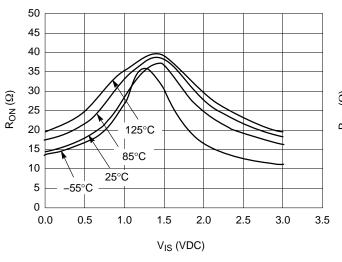
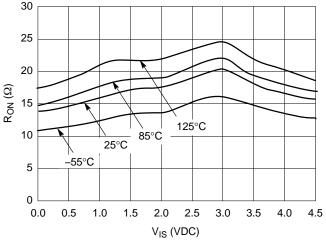
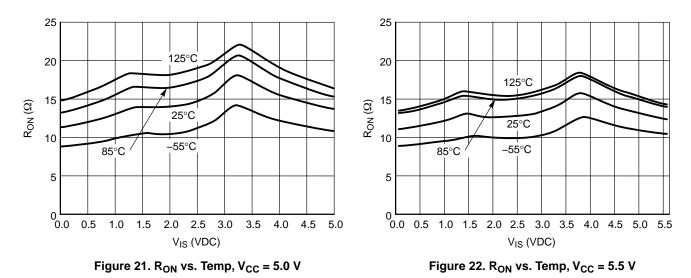


Figure 19. R_{ON} vs. Temp, V_{CC} = 3.0 V

Figure 18. R_{ON} vs. Temp, V_{CC} = 2.5 V







ORDERING INFORMATION

Device Order Number	Package Type	Tape and Reel Shippingize†		
NLAS325USG	US8 (Pb–Free)	3000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

DATE 30 APR 2021

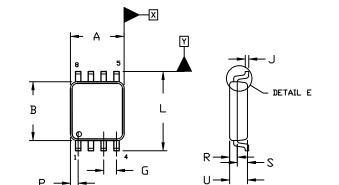




SCALE 4 :1

SEATING PLANE

μD



С

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NDTES

US8 CASE 493 ISSUE E

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DETAIL E

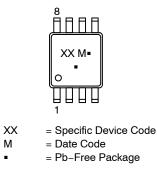
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS

0.10 TYP

- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURR. MOLD FLASH, PROTRUSION, OR GATE BURR SHALL NOT EXCEED 0.14 (0.0055') PER SIDE.
- 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT EXCEED 0.14 (0.0055') PER SIDE.
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM (0.003-0.008*).
- 6. ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 MM (0.002").

	MILLIMETERS		INC	HES	
DIM	MIN.	MAX.	MIN.	MAX.	
A	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
С	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
н	0.40	REF	0.016	REF	
J	0.10	0.18	0.004	0.007	
к	0.00	0.10	0.000	0.004	
L	3.00	3.25	0.118	0.128	
м	0*	6*	0*	6*	
N	0*	10*	0*	10*	
Р	0.23	0.34	0.010	0.013	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024 0.03		
V	0.12	BSC	0.005 BSC		

GENERIC MARKING DIAGRAM*



(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "●", may or may not be present. Some products may not follow the Generic Marking.

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⊕0.10 (0.004) **₩**TXY

0.20

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